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DATA SHEET

INTEGRATED CIRCUITSCB打样工厂, 24小时加急出

SSTVF16857 DDR PC1600-PC3200 14-bit SSTL_2 registered driver with differential clock inputs

Product data

2003 Sep 19







SSTVF16857

FEATURES

- Stub-series terminated logic for 2.5 V V_{DDQ} (SSTL_2)
- Optimized for PC 2700 DDR (Double Data Rate) SDRAM applications
- Suitable for PC1600/PC2100 DDR SDRAM applications
- Suitable for PC3200 applications when used at V_{DD} = 2.6 V
- Inputs compatible with JESD8-9 SSTL_2 specifications.
- Flow-through architecture optimizes PCB layout
- ESD classification testing is done to JEDEC Standard JESD22. Protection exceeds 2000 V to HBM per method A114.
- Latch-up testing is done to JEDEC Standard JESD78, which exceeds 100 mA.
- Full DDR300/333/400 solution @ 2.5V when used with PCKV857
- Available in TSSOP-48, TVSOP-48 and 56 ball VFBGA packages
- Superior VREF noise rejection

DESCRIPTION

The SSTVF16857 is a 14-bit SSTL_2 registered driver with differential clock inputs, designed to operate between 2.3 V and 2.7 V. V_{DDO} must not exceed V_{CC}. Inputs are SSTL_2 type with V_{REF} normally at 0.5*V_{\text{DDQ}}. The outputs support class I which can be used for standard stub-series applications or capacitive loads. Master reset (RESET) asynchronously resets all registers to zero.

The SSTVF16857 is intended to be incorporated into standard DIMM (Dual In-Line Memory Module) designs defined by JEDEC, such as DDR (Double Data Rate) SDRAM or SDRAM II Memory Modules. Different from traditional SDRAM, DDR SDRAM transfers data on both clock edges (rising and falling), thus doubling the peak bus bandwidth. A DDR DRAM rated at 166 MHz will have a burst rate of 333 MT/s (mega-transfers per second). The modules require between 23 and 27 registered control and address lines, so two 14-bit wide devices will be used on each module. The SSTVF16857 is intended to be used for SSTL_2 input and output signals.

The device data inputs consist of differential receivers. One differential input is tied to the input pin while the other is tied to a reference input pad, which is shared by all inputs.

The clock input is fully differential to be compatible with DRAM devices that are installed on the DIMM. However, since the control inputs to the SDRAM change at only half the data rate, the device must only change state on the positive transition of the CLK signal. In order to be able to provide defined outputs from the device even before a stable clock has been supplied, the device must support an asynchronous input pin (reset), which when held to the LOW state will assume that all registers are reset to the LOW state and all outputs drive a LOW signal as well.

QUICK REFERENCE DATA

GND = 0 V; $T_{amb} = 25^{\circ}C$; $t_r = t_f \le 2.5$ ns

SYMBOL	PARAMETER	CONDITIONS	TYPICAL	UNIT
t _{PHL} /t _{PLH}	Propagation delay; CLK to Qn	$C_L = 30 \text{ pF}; V_{DDQ} = 2.5 \text{ V}$	1.9	ns
Cl	Input capacitance	V _{CC} = 2.5 V	2.9	pF

PIN CONFIGURATION

Q1 1	48	D1
Q2 2	47	D2
GND 3	46	GND
V _{DDQ} 4	45	V _{CC}
Q3 5	44	D3
Q4 6	43	D4
Q5 7	42	D5
GND 8	41	D6
V _{DDQ} 9	40	D7
Q6 10	39	CLK-
Q7 [11	38	CLK+
V _{DDQ} 12	37	V _{CC}
GND 13	36	GND
Q8 14	35	V _{REF}
Q9 [15	34	RESET
V _{DDQ} [16	33	D8
GND 17	32	D9
Q10 [18	31	D10
Q11 [19	30	D11
Q12 20	29	D12
V _{DDQ} 21	28	V _{CC}
GND 22	27	GND
Q13 23	26	D13
Q14 24	25	D14
	swoo	0685

ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	ORDER CODE	DWG NUMBER
48-Pin Plastic TSSOP Type I	0 to +70 °C	SSTVF16857DGG	SOT362-1
48-Pin Plastic TSSOP (TVSOP)	0 to +70 °C	SSTVF16857DGV	SOT480-1
56-Ball Plastic VFBGA	0 to +70 °C	SSTVF16857EV	SOT702-1

PIN DESCRIPTION

PIN NUMBER	SYMBOL	NAME AND FUNCTION
34	RESET	LVCMOS asynchronous master reset (Active LOW)
48, 47, 44, 43, 42, 41, 40, 33, 32, 31, 30, 29, 26, 25	D1 - D14	SSTL_2 data inputs
1, 2, 5, 6, 7, 10, 11, 14, 15, 18, 19, 20, 23, 24	Q1 - Q14	SSTL_2 data outputs
35	V _{REF}	SSTL_2 input reference level
3, 8, 13, 17, 22, 27, 36, 46	GND	Ground (0 V)
28, 37, 45	V _{CC}	Positive supply voltage
4, 9, 12, 16, 21	V _{DDQ}	Output supply voltage
38 39	CLK+ CLK-	Differential clock inputs

FUNCTION TABLE

	INPUTS						
RESET	CLK	CLK	D	Q			
L	Х	Х	Х	L			
Н	\downarrow	\uparrow	Н	Н			
Н	\downarrow	\uparrow	L	L			
Н	L or H	L or H	Х	Q ₀			

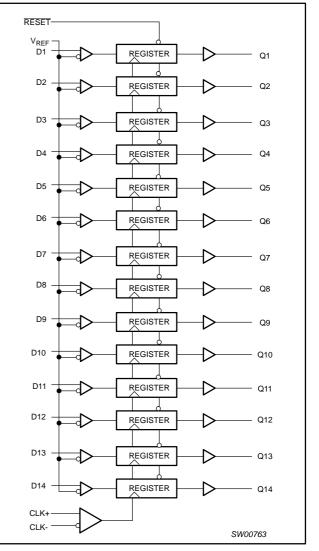
H = High voltage level

L = High voltage level $\downarrow = High-to-Low transition$

 \uparrow = Low-to-High transition

X = Don't care

LOGIC DIAGRAM



SSTVF16857

DDR PC1600-PC3200 14-bit SSTL_2 registered driver with differential clock inputs

BALL CONFIGURATION

	1	2	3	4	5	6
А	Q1	NC	NC	NC	NC	D1
В	GND	Q2	V _{CC}	Vcc	D2	GND
С	Q4	Q3	Q5	D5	D3	D4
D	V _{CC}	GND	Q6	CLK-	D6	D7
E	V _{CC}	Q7			CLK+	V _{CC}
F	GND	Q8			V _{REF}	GND
G	V _{CC}	GND	Q9	RESET	D9	D8
н	Q11	Q12	Q10	D10	D12	D11
J	GND	Q13	V _{CC}	V _{CC}	D13	GND
к	Q14	NC	NC	NC	NC	D14

ABSOLUTE MAXIMUM RATINGS¹

SYMBOL	PARAMETER	CONDITION	L		
STIVIDUL	PARAMETER	CONDITION	MIN	MAX	
V _{CC}	DC supply voltage		-0.5	+4.6	V
I _{IK}	DC input diode current	V ₁ < 0		-50	mA
VI	DC input voltage ³		-0.5	V _{DDQ} + 0.5	V
I _{OK}	DC output diode current	V _O < 0		-50	mA
V _{OUT}	DC output voltage ³		-0.5	V _{DDQ} + 0.5	V
	DC output current	$V_{O} = 0$ to V_{DDQ}	-	±50	
lout	Continuous current ⁴	V _{CC} , V _{DDQ} , or GND	—	±100	mA
T _{stg}	Storage temperature range ²		-65	+150	°C

NOTES:

1. Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

2. The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability. The maximum junction temperature of this integrated circuit should not exceed 150°C.

3. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

4. The continuous current at V_{CC} , V_{DDQ} , or GND should not exceed ±100 mÅ.

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RECOMMENDED OPERATING CONDITIONS¹

SYMBOL	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
V _{CC}	Supply voltage		2.3	2.5	2.7	V
V _{DDQ}	Output supply voltage		2.3	2.5	2.7	V
M	Reference voltage	PC1600-PC2700	1.15	1.25	1.35	V
V_{REF}	$(V_{REF} = 0.5 \times V_{DDQ})$	PC3200	1.25	1.30	1.35	V
V _{TT}	Termination voltage		V _{REF} - 40 mV	V _{REF}	V _{REF} + 40 mV	V
VI	Input voltage		0	_	V _{CC}	V
V _{IH}	AC HIGH-level input voltage	All inputs	V _{REF} + 310 mV	_	—	V
V _{IL}	AC LOW-level input voltage	All inputs	—	_	V _{REF} - 310 mV	V
V _{IH}	DC HIGH-level input voltage	All inputs	V _{REF} + 150 mV	_	V _{DDQ} + 0.5 V	V
VIL	DC LOW-level input voltage	All inputs	V _{SS} - 0.5 V	_	V _{REF} - 150 mV	V
I _{OH}	HIGH-level output current		—	_	-20	mA
I _{OL}	LOW-level output current		—	_	20	mA
T _{amb}	Operating free-air temperature range		0		70	°C

NOTE:

1. Unused control inputs must be held HIGH or LOW to prevent them from floating.

DC ELECTRICAL CHARACTERISTICS—PC1600-PC2700

Over recommended operating conditions. Voltages are referenced to GND (ground = 0 V).

			L				
SYMBOL	PARAMETER	TEST CONDI	TEST CONDITIONS			°C	UNIT
				MIN	TYP ²	MAX	
V _{IK}	I/O supply voltage	V _{CC} = 2.3 V; I _I = -18 mA		_	—	-1.2	
M		V_{CC} = 2.3 V to 2.7 V; I_{OH} = -100 $$	μΑ	V _{CC} - 0.2	—	_	V
Vон	HIGH-level output voltage	$V_{CC} = 2.3 \text{ V}; I_{OH} = -16 \text{ mA}$		1.95	—	_	
V	LOW-level output voltage	V_{CC} = 2.3 V to 2.7 V; I_{OL} = 100 $\mu \mu$	Ą	_	—	0.2	V
V _{OL}	LOW-level output voltage	$V_{CC} = 2.3 \text{ V}; \text{ I}_{OL} = 16 \text{ mA}$		—	—	0.35	v
V _{CMR}	CLK, CLK	Common mode range for reliable	performance	0.97	—	1.53	V
V _{PPmim}	CLK, CLK	Minimum peak-to-peak input to en	nsure logic state	_	—	360	mV
	Data inputs, RESET	V_{CC} = 2.7 V; V_{I} = 1.7 V or 0.8 V	V _{REF} = 1.15 V or 1.35 V	_	0.01	±5	μA
	Data Inputs, RESET	V_{CC} = 2.7 V; V _I = 2.7 V or 0 V		_	0.01	±5	μΑ
կ	CLK, CLK	V_{CC} = 2.7 V; V_{I} = 1.7 V or 0.8 V	V = 1.15 V or 1.25 V	_	0.05	±5	
	ULK, ULK	V_{CC} = 2.7 V; V_{I} = 2.7 V or 0 V	V _{REF} = 1.15 V or 1.35 V	_	0.05	±5	μA
	V _{REF}	$V_{CC} = 2.7 V$	V_{REF} = 1.15 V or 1.35 V	—	0.05	±5	μA
	Quiescent supply current	V_{CC} = 2.7 V; V_{I} = 1.7 V or 0.8 V	RESET = GND	—	0.5	10	μΑ
Icc	CLK and CLK in opposite state ¹	V_{CC} = 2.7 V; V_{I} = 2.7 V or 0 V	$\overline{\text{RESET}} = V_{CC}$	_	10	25	mA
	Data inputs	$ V_{I} = V_{REF} \pm 310 \text{ mV}, \\ V_{CC} = 2.5 \text{ V} $	V _{REF} = 1.15 V or 1.35 V	2.5	2.9	3.4	
CI	CLK, CLK	V_{ICR} = 1.25 V, $V_{I(PP)}$ = 360 mV, V_{CC} = 2.5 V	V _{REF} = 1.15 V or 1.35 V	2.5	2.9	3.4	pF
	RESET	$V_I = V_{CC}$ or GND, $V_{CC} = 2.5$ V	V_{REF} = 1.15 V or 1.35 V	2.5	2.9	3.4	

NOTES:

1. When CLK and $\overline{\text{CLK}}$ are HIGH, typical I_{CC} = 25 mA. 2. All typical values are at V_{CC} = 2.5 V and T_{amb} = 25 °C (unless otherwise specified).

SSTVF16857

DC ELECTRICAL CHARACTERISTICS—PC3200

Over recommended operating conditions. Voltages are referenced to GND (ground = 0 V).

				L	IMITS		
SYMBOL	PARAMETER	TEST CONDI	Temp = 0 to +70 °C			UNIT	
				MIN	TYP ²	MAX	
V _{IK}	I/O supply voltage	V _{CC} = 2.5 V; I _I = -18 mA			—	-1.2	
V	HIGH-level output voltage	V_{CC} = 2.5 V to 2.7 V; I_{OH} = -100	μA	V _{CC} - 0.2	—	—	V
V _{OH}	HIGH-level output voltage	$V_{CC} = 2.5 \text{ V}; \text{ I}_{OH} = -16 \text{ mA}$		1.95	—	—	
M	LOW-level output voltage	V_{CC} = 2.5 V to 2.7 V; I_{OL} = 100 μ /	4		—	0.2	V
V _{OL}	LOW-level output voltage	V _{CC} = 2.5 V; I _{OL} = 16 mA			—	0.35	V
V _{CMR}	CLK, CLK	Common mode range for reliable	performance	0.97	—	1.53	V
V _{PPmim}	CLK, CLK	Minimum peak-to-peak input to er	nsure logic state	—	—	360	mV
	Data inputs, RESET	V_{CC} = 2.7 V; V _I = 1.7 V or 0.8 V	V _{REF} = 1.25 V or 1.35 V		0.01	±5	
	Data inputs, RESET	V_{CC} = 2.7 V; V _I = 2.7 V or 0 V			0.01	±5	μA
lj	CLK, CLK	V_{CC} = 2.7 V; V _I = 1.7 V or 0.8 V	1 25 V or 1 25 V	—	0.05	±5	
	ULN, ULN	V_{CC} = 2.7 V; V_{I} = 2.7 V or 0 V	V _{REF} = 1.25 V or 1.35 V	_	0.05	±5	μA
	V _{REF}	$V_{CC} = 2.7 V$	V_{REF} = 1.25 V or 1.35 V	—	0.05	±5	μΑ
	Quiescent supply current	V_{CC} = 2.7 V; V _I = 1.7 V or 0.8 V	RESET = GND	—	0.5	10	μA
I _{CC}	CLK and CLK in opposite state ¹	V_{CC} = 2.7 V; V_{I} = 2.7 V or 0 V	$\overline{\text{RESET}} = V_{CC}$	—	10	25	mA
	Data inputs	$V_{I} = V_{REF} \pm 310 \text{ mV},$ $V_{CC} = 2.6 \text{ V}$	V _{REF} = 1.25 V or 1.35 V	2.5	2.9	3.4	
CI	CLK, CLK	V_{ICR} = 1.25 V, $V_{I(PP)}$ = 360 mV, V_{CC} = 2.6 V	V_{REF} = 1.25 V or 1.35 V	2.5	2.9	3.4	pF
	RESET	$V_I = V_{CC}$ or GND, $V_{CC} = 2.6$ V	V_{REF} = 1.25 V or 1.35 V	2.5	2.9	3.4	

NOTES:

1. When CLK and $\overline{\text{CLK}}$ are HIGH, typical I_{CC} = 25 mA. 2. All typical values are at V_{CC} = 2.6 V and T_{amb} = 25 °C (unless otherwise specified).

TIMING REQUIREMENTS—PC1600-PC2700

Over recommended operating conditions; Tamb = 0 to +70 °C (unless otherwise noted) (see Figure 1)

			LIM	UNIT	
SYMBOL	PARAMETER	TEST CONDITIONS	V _{CC} = 2.5		
			MIN	MAX	
f _{clock}	Clock frequency		200	MHz	
t _w	Pulse duration, CLK, CLK HIGH or LC	W	1.0		ns
+	Sotup time	Data before CLK \uparrow , CLK \downarrow	0.2	_	20
t _{su}	Setup time	RESET HIGH before CLK^{\uparrow} , $\overline{CLK}^{\downarrow}$	0.8	_	ns
t _h	Hold time		0.75	_	ns

TIMING REQUIREMENTS—PC3200

Over recommended operating conditions; T_{amb} = 0 to +70 °C (unless otherwise noted) (see Figure 1)

			LIM	UNIT		
SYMBOL	PARAMETER	TEST CONDITIONS	V _{CC} = 2.5			
			MIN	MAX		
f _{clock}	Clock frequency	—	210	MHz		
t _w	Pulse duration, CLK, CLK HIGH or LO	1.0	—	ns		
	Cotup time	Data before CLK↑, <u>CLK</u> ↓	0.2	—		
t _{su}	Setup time	RESET HIGH before CLK [↑] , \overline{CLK}	0.8	—	ns	
t _h	Hold time		0.75	—	ns	

SWITCHING CHARACTERISTICS—PC1600-PC2700

Over recommended operating conditions; $T_{amb} = 0$ to +70 °C; $V_{DDQ} = 2.3 - 2.7$ V and V_{DDQ} does not exceed $V_{CC.}$ Class I, $V_{REF} = V_{TT} = V_{DDQ} \times 0.5$ and $C_L = 10$ pF (unless otherwise noted) (see Figure 1)

	FROM (INPUT)		LIMITS		UNIT
SYMBOL		TO (OUTPUT)	V_{CC} = 2.5 V ±0.2 V		
			MIN	MAX	
f _{max}	Maximum clock frequency		200	—	MHz
t _{PLH} /t _{PHL}	CLK and CLK	Q	1.0	2.6	ns
t _{PHL}	RESET	Q	2.0	4.0	ns

SWITCHING CHARACTERISTICS—PC3200

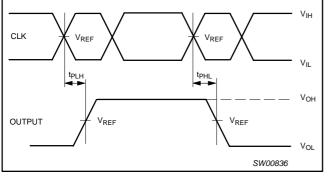
Over recommended operating conditions; $T_{amb} = 0$ to +70 °C; $V_{DDQ} = 2.3 - 2.7$ V and V_{DDQ} does not exceed $V_{CC.}$ Class I, $V_{REF} = V_{TT} = V_{DDQ} \times 0.5$ and $C_L = 10$ pF (unless otherwise noted) (see Figure 1)

	FROM (INPUT)		LIMITS		UNIT
SYMBOL		TO (OUTPUT)	V_{CC} = 2.5 V ± 0.2 V		
		(,	MIN	MAX	
f _{max}	Maximum clock frequency		210	—	MHz
t _{PLH} /t _{PHL}	CLK and CLK	Q	1.0	2.6	ns
t _{PHL}	RESET	Q	2.0	4.0	ns

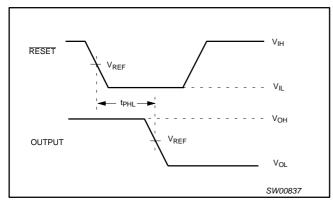
SSTVF16857

PARAMETER MEASUREMENT INFORMATION

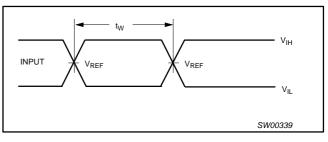
AC WAVEFORMS



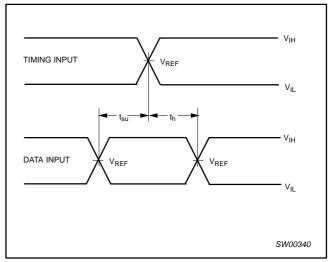
Waveform 1. Propagation delay times



Waveform 2. Propagation delay RESET to output.



Waveform 3. Pulse duration



Waveform 4. Setup and hold times

TEST CIRCUIT

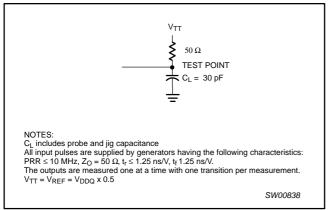
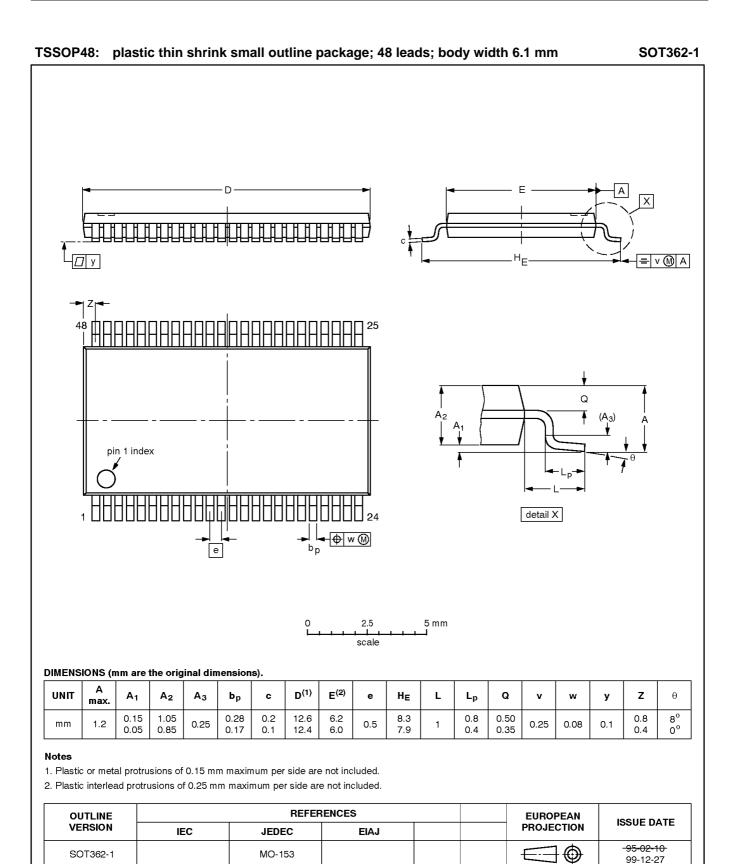


Figure 1. Load circuitry

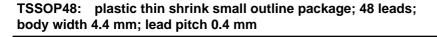


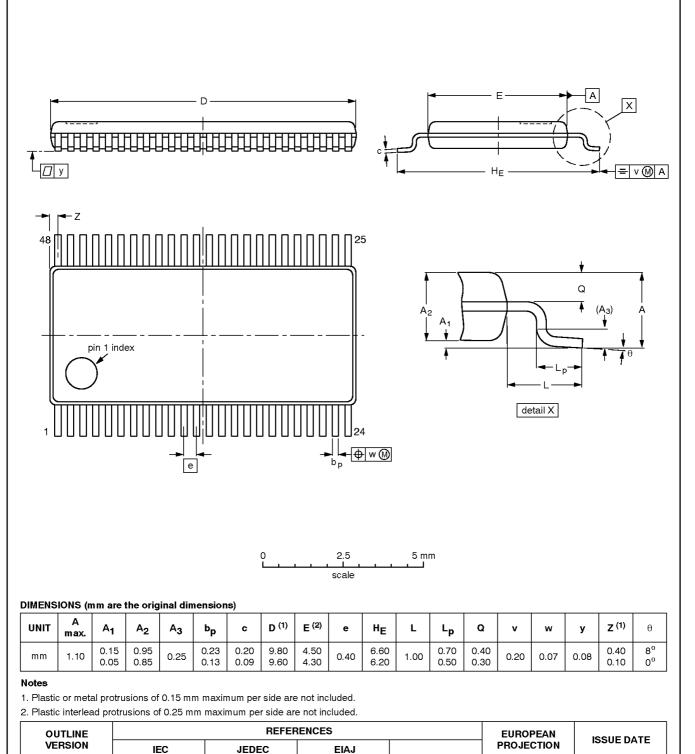
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Product data

SOT480-1

DDR PC1600-PC3200 14-bit SSTL_2 registered driver with differential clock inputs





MO-153

DSTL_2

Product data

SOT480-1

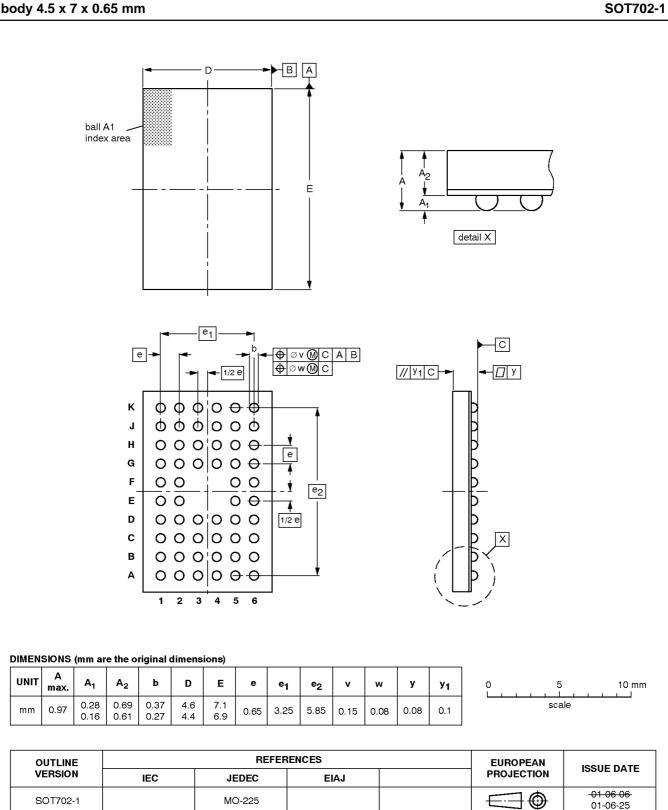
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VFBGA56: plastic very thin fine-pitch ball grid array package; 56 balls; body 4.5 x 7 x 0.65 mm

Product data

REVISION HISTORY

R	ev	Date	Description
_	1		Product data (9397 750 12077); ECN 853-2405 30362 dated 18 September 2003.

SSTVF16857

DDR PC1600-PC3200 14-bit SSTL 2 registered driver with differential clock inputs

Data sheet status

Level	Data sheet status ^[1]	Product status ^{[2] [3]}	Definitions
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
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Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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